

Qualified Vendors List (QVL)

Memory modules listed below are for reference only. Due to massive memory models on the market, we can only verify some of them.

下列的記憶體模組僅供參考，因市面上的記憶體模組眾多，我們無法一一驗證。

Model Name: GC230D DDR2 533

| Size | Module Supplier | Module P/N. | SS/DS | Comp. Used | Component P/N. | Single-channel |
|-------|-----------------|-----------------------|-------|------------|-------------------------|----------------|
| 256MB | A-DATA | M20MI2F3G3110A1B0Z | SS | MICRON | 4JB11 D9CHM | v |
| 2GB | A-DATA | M2OAD2H3J4140A1B0Z | DS | A-DATA | U52118A0WCS3 | v |
| 512MB | BUFFALO | 450712 D2/533-512M*2 | SS | MICRON | 5MB42D9DCN | v |
| 256MB | Elixir | M2U25664TUH4A0F-37B | SS | Elixir | N2TU51216AF-37B | v |
| 512MB | Elixir | M2U51264TU88A0F-37B | SS | Elixir | N2TU51280AF-37B | v |
| 512MB | GOODRAM | GR533DD64L4/512 | SS | AENEON | AET93F370 0514 | v |
| 256MB | Kingston | KVR533D2N4/256 | SS | ELPIDA | E5116AF-5C-E | v |
| 512MB | Kingston | KVR533D2N4/512 | SS | Infineon | HYB18T512800AF37 | v |
| 1GB | Kingston | KVR533D2N4/1G | DS | Micron | 5VD11 D9GCT | v |
| 512MB | MICRON | MT16HTF6464AG-52EB2 | DS | MICRON | 3YB11 Z9BQT | v |
| 1GB | MICRON | MT16HTF12864AY-53EA1 | DS | MICRON | 4JA11 D9CRZ | v |
| 2GB | MICRON | MT16HTF25664AY-53EE1 | DS | MICRON | 6XE11 D9HNH | v |
| 512MB | Pmi | 6408GATA05-04B1 | SS | SAMSUNG | K4T51083QB-GCD5 | v |
| 512MB | Veritech | GTP512HLTTG6DG | SS | Veritech | VTD2644M8PC6G | v |
| 256MB | Kingmax | KLBB68F-36EP4 | SS | ELPIDA | E5116AB-5C-E 0518 | v |
| 512MB | Kingmax | KLBC28F-A8EB4 | SS | ELPIDA | E5108AE-5C-E | v |
| 1GB | Kingmax | KLBD48F-A8EB4 | DS | ELPIDA | E5108AE-5C-E | v |
| 512MB | Kingmax | KLBC28KA8HD4 | SS | Hynix | HY5PS12821 F-C4 517A | v |
| 1GB | Kingmax | KLBD48K-A8HD4 HHES | DS | Hynix | HY5PS12821 F-C4 509A | v |
| 1GB | NANYA | NT1GT64U8HA0BY-37B | DS | NANYA | NT5TU64MBAE-37B | v |
| 1GB | SAMSUNG | M378T2953CZ0-CD5 0522 | DS | SAMSUNG | K4T51083QC-519 ZCD5 | v |
| 1GB | Infineon | HYS64T128020HU-3.7-B | DS | Infineon | HYB18T512800BF37 | v |
| 512MB | PSC | | SS | PSC | A3R12E3EDF-G5C 505ACA00 | v |
| 256MB | CORSAIR | CM2X256-4300 | DS | | | v |
| 512MB | CORSAIR | CM2X512-4300 | DS | | | v |
| 1GB | AENEON | AET760UD00-370A98X | DS | AENEON | AET93F370A | v |
| 2GB | AENEON | AET860UD00-370A08X | DS | AENEON | AET03F370 | v |

Model Name: GC230D DDR2 400

| Size | Module Supplier | Module P/N. | SS/DS | Comp. Used | Component P/N. | Single-channel |
|-------|-----------------|---------------------|-------|------------|------------------|----------------|
| 256MB | SAMSUNG | M378T3253FG0-CCC | SS | SAMSUNG | K4T56083QF-GCCC | v |
| 512MB | SAMSUNG | M391T6553BG0-CCC | SS | SAMSUNG | K4T51083QB-GCCC | v |
| 1GB | AENEON | AET660UD00-500A08X | SS | AENEON | AET03F50C | v |
| 512MB | NANYA | NT152T64U88A0F-5A | SS | NANYA | NT5TU64M8AF-5A | v |
| 512MB | MICRON | MT16HTF6464AG-40EB2 | SS | MICRON | 4AB11 Z9BSJ (ES) | v |
| 256MB | NANYA | NT256T64UH4A0F-5A | SS | NANYA | NT5TU32M16AF-5A | v |
| 256MB | Infineon | HYS64T32000HU-5-A | SS | Infineon | HYB18T512160AF-5 | v |